

### **Description**

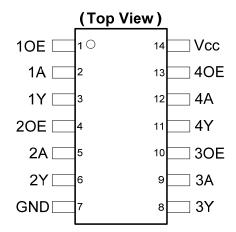
The 74AHCT126 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a low logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 4.5V to 5.5V.

#### **Features**

Notes:

- Wide Supply Voltage Range from 4.5V to 5.5V
- Inputs Are TTL Voltage Level Compatible
- Outputs Sink or Source 8mA at V<sub>CC</sub> = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Pin Assignments**



SO-14 / TSSOP-14

### **Applications**

- General Purpose Logic
- Wide array of products such as:
  - PCs, Networking, Notebooks, Netbooks
  - Computer Peripherals, Hard Drives, CD/DVD ROM
  - TV, DVD, DVR, Set Top Box

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) an <1000ppm antimony compounds.</li>

Click here for ordering information, located at the end of datasheet



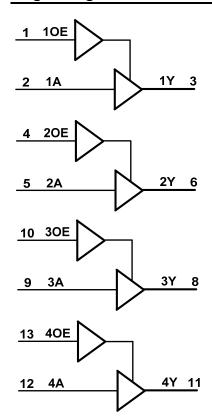
## **Pin Descriptions**

Pin Number	Pin Name	Function
1	10E	Data Enable Input (active low)
2	1A	Data Input
3	1Y	Data Output
4	20E	Data Enable Input (active low)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	30E	Data Enable Input (active low)
11	4Y	Data Output
12	4A	Data Input
13	40E	Data Enable Input (active low)
14	V <sub>CC</sub>	Supply Voltage

## **Function Table**

Inp	Output	
OE	Α	Y
L	Н	Н
L	L	L
Н	Х	Z

## **Logic Diagram**



# Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	ESD CDM Charged Device Model ESD Protection		KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
lık	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < 0 V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub>	20	mA
Io	Continuous Output Current 0V < V <sub>O</sub> < V <sub>CC</sub>	+/- 25	mA
Icc	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	T <sub>STG</sub> Storage Temperature		°C
Ртот	Total Power Dissipation	500	mW

Note:

<sup>4.</sup> Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



## Recommended Operating Conditions (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
Vcc	Supply Voltage	4.5	5.5	V
VI	Input Voltage	0	5.5	V
Vo	Output Voltage	0	V <sub>CC</sub>	V
Δt/ΔV	Input transition Rise or Fall Rate		20	ns/V
TA	Operating Free-Air Temperature	-40	+125	°C

Note: 5. Unused inputs should be held at  $V_{\text{CC}}$  or Ground.

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Comple at	Donomoton	Test Conditions	Voc	T <sub>A</sub> = -40°0	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		
Symbol	Parameter	rest Conditions	Vcc	Min	Max	Min	Max	Unit	
V <sub>IH</sub>	High-Level Input Voltage		4.5V to 5.5V	2.0		2.0		٧	
V <sub>IL</sub>	Low-Level Input Voltage		4.5V to 5.5V		0.8		0.8	V	
High-Level Out	High-Level Output	I <sub>OH</sub> = -50μA	4.5V	4.4		4.4		V	
V <sub>OH</sub>	Voltage	I <sub>OH</sub> = -8mA	4.5V	3.80		3.70		V	
.,	Low-Level Output Voltage	I <sub>OL</sub> = 50μA	4.5V		0.1		0.1	V	
V <sub>OL</sub>		I <sub>OL</sub> = 8mA	4.5V		0.44		0.55		
loz	Z State Leakage Current	V <sub>O</sub> = 0 to 5.5V	5.5V		±2.5		±10	μΑ	
II	Input Current	V <sub>I</sub> = GND to 5.5V	3.6V		±1		±2	μA	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	3.6V		20		40	μA	
ΔI <sub>CC</sub>	Additional Supply Current	One input at V <sub>CC</sub> –2.1V Other pins at V <sub>CC</sub> or GND	5.5V		1.35		5	mA	

## **Operating Characteristics**

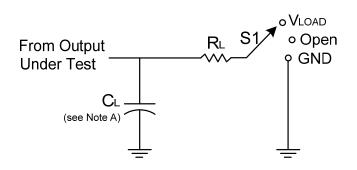
Parameter		Test	V <sub>CC</sub> = 5.5V	Unit
		Conditions	Тур	O i ii c
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	f = 1MHz	14.8	pF
C <sub>i</sub>	Input Capacitance	$V_i = V_{CC} - or$ GND	4.0	pF

## **Switching Characteristics** (V<sub>CC</sub> = 4.5V to 5.5V)

Symbol	Parameter	Test Conditions	T <sub>A</sub> = +25°C		-40°C to +85°C		-40°C to +125°C		Unit	
Symbol	Parameter	rest Conditions	Min	Тур	Max	Min	Max	Min	Max	Ullit
		Figure 1 C <sub>L</sub> = 15pF	0.5	3.0	5.5	0.5	6.5	0.5	7.0	
ĮPD.	t <sub>PD</sub> Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 50pF	0.5	4.3	7.5	0.5	8.5	0.5	9.5	ns
	Enable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15 pF	0.5	3.3	5.1	0.5	6.0	0.5	6.5	20
t <sub>EN</sub>	Enable Time OEN to 1N	Figure 1 C <sub>L</sub> = 50pF	0.5	4.7	7.1	0.5	8.0	0.5	9.0	ns
4	Disable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF	0.5	4.8	6.8	0.5	8.0	0.5	8.5	no
t <sub>DIS</sub>	DISABLE TIME OEN TO TN	Figure 1 C <sub>L</sub> = 50pF	0.5	6.5	8.9	0.5	10.0	0.5	11.5	ns

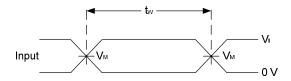


#### **Parameter Measurement Information**

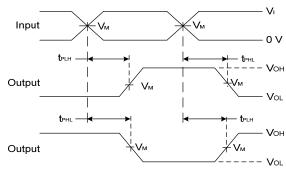


TEST	<b>S1</b>
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	Vload
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

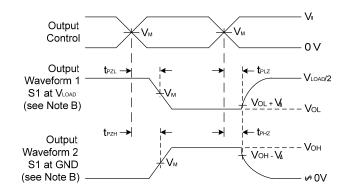
Vcc	Inp	outs	V <sub>M</sub>	V <sub>M</sub>	V		Б	V/A
VCC	VI	t <sub>r</sub> /t <sub>f</sub>	Inputs	Outputs	S VLOAD	CL	KL	<b>V</b> Δ
4.5V to 5.5V	3 V	≤3ns	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub>	15pF, 50pF	1K	0.3V



#### Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

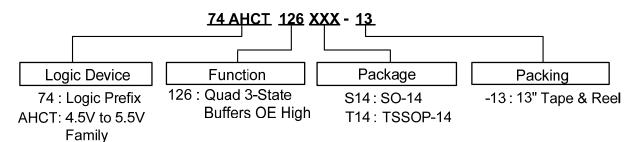
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis.}$
- E. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>EN0</sub>
- F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD.}$



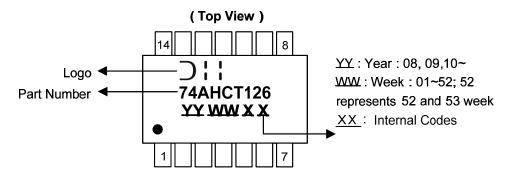
### **Ordering Information**



	Part Number	Package Code	Pookoging	7" Tape a	and Reel
	Part Number	Package Code	Packaging	Quantity	Part Number Suffix
Green	74AHCT126S14-13	S14	SO-14	2500/Tape & Reel	-13
Green	74AHCT126T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

### **Marking Information**

(1) SO-14, TSSOP-14



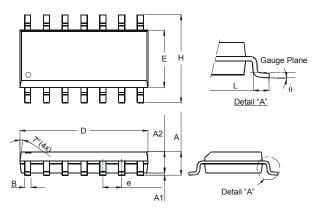
Part Number	Package
74AHCT126S14	SO-14
74AHCT126T14	TSSOP-14



## Package Outline Dimensions (All dimensions in mm.)

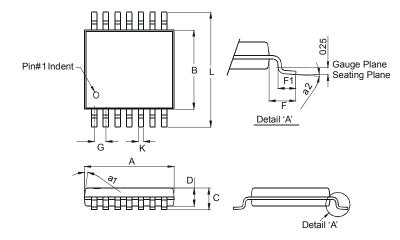
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-14



	SO-14	
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45	Тур
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27	Тур
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Din	nensions	in mm

### Package Type: TSSOP-14



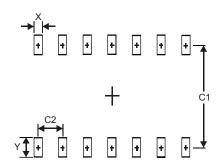
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	_	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



## **Suggested Pad Layout**

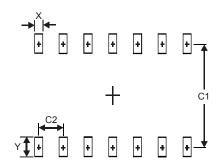
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### Package Type: SO-14



Dimensions	Value (in mm)	
Х	0.60	
Υ	1.50	
C1	5.4	
C2	1.27	

#### Package Type: TSSOP-14



Dimensions	Value (in mm)	
Х	0.45	
Υ	1.45	
C1	5.9	
C2	0.65	



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